TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSVI)

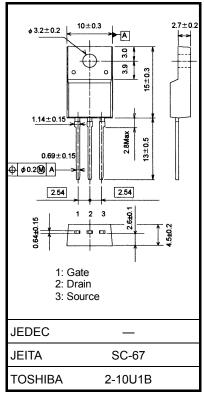
# 2SK3561

#### Switching Regulator Applications

- Low drain-source ON resistance: R<sub>DS</sub> (ON) = 0.75 Ω (typ.)
- High forward transfer admittance: |Y<sub>fs</sub>| = 6.5 S (typ.)
- Low leakage current: I<sub>DSS</sub> = 100 μA (V<sub>DS</sub> = 500 V)
- Enhancement mode:  $V_{th}$  = 2.0 to 4.0 V (V<sub>DS</sub> = 10 V, I<sub>D</sub> = 1 mA)

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	500	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		V <sub>DGR</sub>	500	V
Gate-source voltage		V <sub>GSS</sub>	±30	V
Drain current	DC (Note 1)	ID	8	
	Pulse (t = 1 ms) (Note 1)	I <sub>DP</sub>	32	A
Drain power dissipation (Tc = $25^{\circ}$ C)		PD	40	W
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	312	mJ
Avalanche current		I <sub>AR</sub>	8	А
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	4	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C



Weight : 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

#### **Thermal Characteristics**

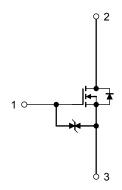
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	3.125	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}(\text{initial}), \text{ L} = 8.3 \text{ mH}, \text{ I}_{AR} = 8 \text{ A}, \text{ R}_{G} = 25 \Omega$ 

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.



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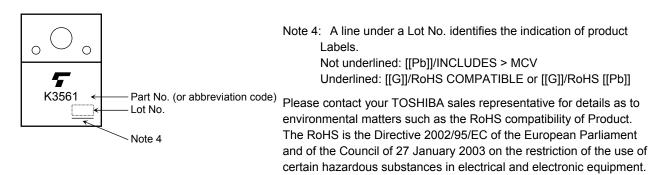
**Electrical Characteristics (Ta = 25°C)** 

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm 25~V,~V_{DS}=0~V$	_		±10	μA
Gate-source breakdown voltage		V (BR) GSS	$I_G=\pm 10~\mu A,~V_{DS}=0~V$	±30			V
Drain cut-off current		IDSS	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			100	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	500			V
Gate threshold ve	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	resistance	R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$		0.75	0.85	Ω
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$	3.0	6.5	_	S
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		1050		pF
Reverse transfer capacitance		C <sub>rss</sub>		_	10		
Output capacitance		C <sub>oss</sub>			110		
Switching time	Rise time	tr	$V_{GS}$ $0 V$ $V_{GS}$ $0 V$ $V_{GS}$ $0 V$ $V_{DD} \simeq 200 V$		26	_	ns
	Turn-on time	t <sub>on</sub>			45		
	Fall time	t <sub>f</sub>			38	_	
	Turn-off time	t <sub>off</sub>	Duty $\leq$ 1%, t <sub>w</sub> = 10 $\mu$ s	_	130		
Total gate charge		Qg		_	28	_	
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \simeq 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 8 \text{ A}$	_	16	_	nC
Gate-drain charge		Q <sub>gd</sub>	1	_	12	_	

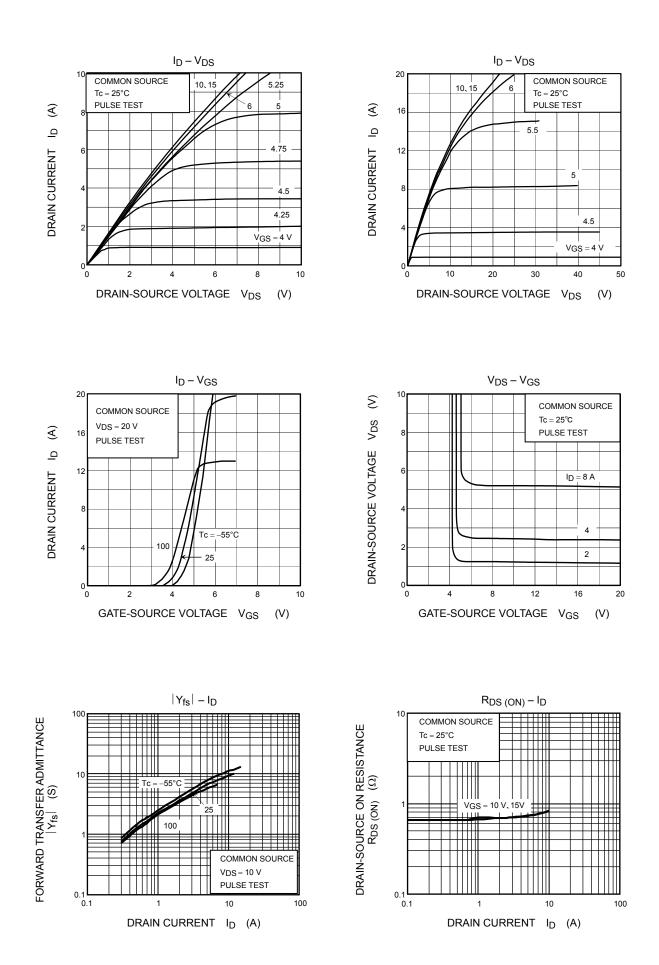
#### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—	_	_	8	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	—	_	_	32	А
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 8 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 8 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dl <sub>DR</sub> /dt = 100 A/μs	_	10	_	μC

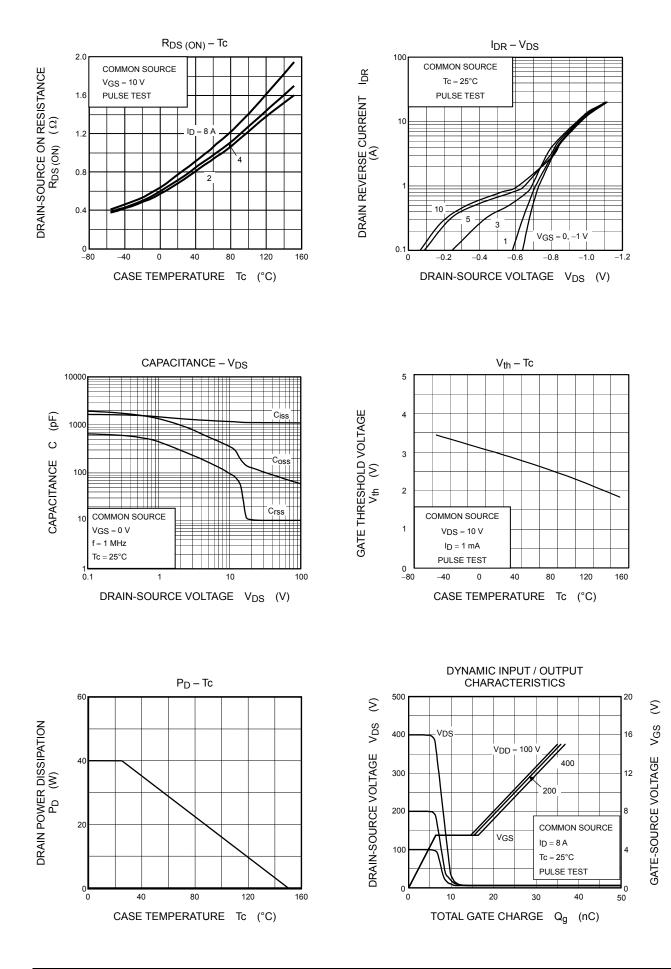
#### Marking

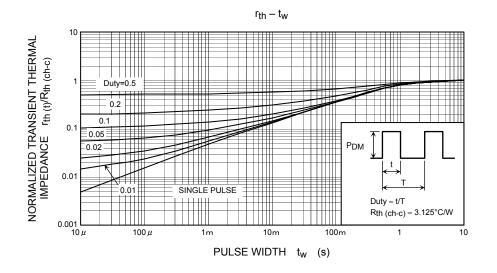


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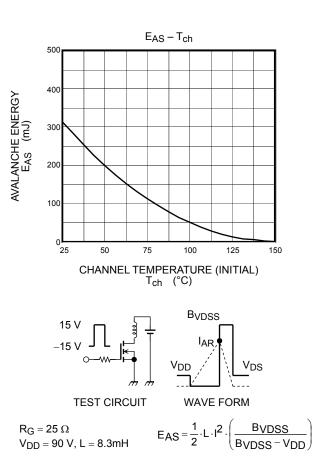


## **TOSHIBA**





SAFE OPERATING AREA 100 ID max (PULSED) 100 μs ID max (CONTINUOUS  $\overline{\mathsf{A}}$ 10 ms DRAIN CURRENT ID DC OPERATION  $Tc = 25^{\circ}C$ **※** SINGLE NONREPETITIVE PULSE 0.1 Tc=25°℃ CURVES MUST BE DERATED LINEARLY WITH INCREASE IN TEMPERATURE. VDSS max 0.01 10 100 1000 DRAIN-SOURCE VOLTAGE VDS (V)



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